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DOI:

10.1016/j.solener.2019.02.010

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Document Version
Peer reviewed version

Citation for published version (Harvard):

Guerriero, P, Tricoli, P & Daliento, S 2019, 'A bypass circuit for avoiding the hot spot in PV modules', *Solar Energy*, vol. 181, pp. 430-438. https://doi.org/10.1016/j.solener.2019.02.010

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A Bypass Circuit for Avoiding the Hot Spot in PV Modules

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Abstract

The hot spot occurring in outlier solar cells is recognized as one of the main reliability issues for photovoltaic modules. Even though PV modules are qualified to sustain over-temperatures the hot spot can lead to accelerated aging and, sometimes, to unexpected failure; in severe cases, with the possible risk of fire. The standard countermeasure to contrast this phenomenon is the adoption of bypass diodes, whose role is to limit the maximum reverse voltage across outlier cells. However, since the current is not limited, power dissipation can be high. In this paper a bypass circuit, suited to completely avoiding the onset of the hot spot, is presented. The circuit is a substantial improvement of a previous version that was able to reduce power dissipation by reducing the voltage across the reverse biased solar cell. The improvement presented in this paper allow to completely cancel the current, thus avoiding power dissipation and, therefore, preventing the rising in temperature of the solar cell. The novelty with respect to comparable approaches is that the intervention of the circuit doesn't require the preliminary detection of the hot spot. Indeed, the circuit self-activates in the same operating conditions of standard diodes, without needing neither control logic nor power supply. Detailed circuit simulations and experiments are presented to evidence the capability of the circuit to fully prevent power dissipation, and consequent rising in temperature, in outlier cells.

Keywords: hot spot, bypass diode, reliability, PV systems.

I. Introduction

In the last years the Photovoltaic (PV) technology experienced a huge increase of the installed capacity. In many countries the achievement of the fuel parity pushed large investments in the construction of new photovoltaic plants, as witnessed by the increment of tens of Gigawatt installed worldwide last year(Philipps and Warmuth, 2018). Among other factors, one of the key points which favored the success of this technology is its modularity, which makes the construction of utility scale power stations almost as easy as small scale domestic plants, with very reduced time to market. However, this strength is the major

weakness of the PV technology as well; in fact, the modularity means that thousands of elements (photovoltaic modules, which are in turn made of tens of series connected solar cells (Green, 1986)), are hardwired to build the desired power size. The consequence is that both fault location and fault fixing are extremely challenging and time-consuming issues. By taking in mind that the Return Of Investment (ROI), is not only dependent on the expected lifetime of the power plant, but also on the continuity of the power production, it is clear that plant shutdown for maintenance interventions should be avoided or, at least, minimized. It is quite obvious that the best strategy to prevent production losses, and consequent maintenance queries, is to improve the reliability of photovoltaic modules. In this regard, it is widely recognized that one of the main issues (Jordan and Kurtz, 2013; Kaplani, 2012; Sanchez-Friera et al., 2011) affecting the probability of faults in photovoltaic modules is the formation of hot spots (García et al., 2013), that is over-temperature typically localized on a portion of a solar cell. It should be remarked that the occurrence of hot spots is absolutely usual during normal operation of PV fields; indeed, the rising in temperature can be triggered by the simple presence of partial shading, even of very small area, like that caused by leaves or birth drops. In such conditions, in fact, solar cells get reverse biased, thus dissipating power and getting hot. In order to limit the maximum reverse bias, photovoltaic modules are equipped with bypass diodes that, as well explained in (Green, 1986), automatically turns on in presence of current mismatches. Unfortunately, bypass diodes cannot avoid the hot spot (Kim and Krein, 2015)occurrence. This fact means that photovoltaic modules should be manufactured to sustain over-temperatures without damages. In principle, the ability to sustain hot spots is certified for each model of commercially available photovoltaic module, by the qualification procedure dictated by the EN 61215 rules. This procedure verifies that the power dissipated by the hot spot cell, depending on the correct sizing of the bypass diode ("AN3432 ST Application note," 2011), is low enough to avoid failures. However, it has been evidenced (Kim and Krein, 2015) that, due to the spread of solar cell parameters, damages can occur even though operating conditions are within expected safe limits. Moreover, it should be considered that recurring hot spot events can lead to accelerated ageing (Olalla et al., 2018), thus increasing the fault probability. Above arguments lead to the conclusion that the over-temperature should be limited as much as possible. As mentioned above the main protecting strategy involves the adoption of bypass diodes. Indeed, as it is widely known, almost all crystalline photovoltaic modules are equipped with such diodes. Even though, as clarified in (Kim and Krein, 2015), they cannot avoid the hot spot, but just limit power dissipation, they have the fundamental feature to be fully compatible with the normal operation of photovoltaic modules, by automatically activating themselves only when, because of some current mismatch, the voltage supplied by the photovoltaic module reverses. Actually, whether or not the bypass diode, in case of mismatch, turns ON, is largely due the control algorithms for the Maximum Power Point Tracking

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71 (MPPT). These algorithms can decide to lower the overall current delivered by the PV system, thus 72 avoiding the turning ON of the bypass diode and the consequent reverse biasing of the outlier solar cell. 73 Thus, a strategy which is encountering some success for limiting the hot spot, is based on the ability to 74 recognize its occurrence so as to instruct the MPPT to keep the operating point of the system in a safe 75 region (Spanoche et al., 2013). For example, in (Bressan et al., 2018) a shadow emulator based on FPGA 76 is exploited to foresee the possible occurrence of hot spot. The limit of this approach is that it does not 77 work for unexpected shadows coming from rubbish covering the cell; moreover, in such approaches, the 78 power delivered by the whole system is dramatically reduced, because the current is limited to that 79 supplied by the worst performing solar cell. 80 Different strategies presented so far involve improved bypass circuits able to reduce (or even suppress) the 81 power dissipated in the reverse biased solar cell (D'Alessandro et al., 2014; Ghanbari, 2017; Niazi et al., 82 2018). 83 In this regard, it should be noted that power dissipation can be totally avoided by forcing the current to 84 zero. Such a feature can be achieved by inserting a series switch for breaking the circuit when the 85 conditions for the triggering of the hot spot are recognized, as for example proposed in (Dhimish et al., 86 2018). In such a case the key point is the reliable detection of unsafe operating conditions. In (Dhimish et 87 al., 2018) thermal images were exploited to directly identify hot cells; after that, a series connected power 88 MOSFET was driven in the OFF state. A more effective detection system was presented in (Kim et al., 89 2013), where the change of impedance of the monitored PV string is assumed as a sign of the presence of 90 the hot spot. The detection required to periodically interrupt the MPPT to acquire the I-V curve of the 91 string. When the hot spot is detected the current is interrupted by means of a series MOSFET. The 92 drawback of this approach is that requires a microprocessor for each photovoltaic module; moreover, its 93 effectiveness depends on the frequency of the I-V scan, in other words, the hot spot is not prevented, it is 94 just suppressed some amount of time after its appearing. 95 In order to overcome the above drawback and with the aim to combine the benefits of the series switch with the self-activation of the standard bypass diode, a modified bypass circuit was presented in (Daliento 96 97 et al., 2016). It exploited the decreasing voltage across the shaded photovoltaic module to drive in the 98 pinch-off operating region a series connected MOSFET. As a result, the reverse voltage appearing across 99 the shaded solar cell was diminished by the drain to source voltage of the MOSFET, thus transferring 100 dissipated power from the solar cell to the power MOSFET. By adopting that circuit, the temperature of 101 the hot cell decreased of some tens of Celsius degree; however, over-temperature was not completely 102 avoided and the warming of the junction box (where the MOSFET was hosted) was a critical issue.

In this paper a substantial improvement of the circuit proposed in (Daliento et al., 2016) is presented. Differently from the previous solution, the new bypass circuit is able to completely suppress the current flowing into the reverse biased solar cell. Therefore, power dissipation cannot occur and the rising in temperature is fully prevented. As a result, the onset of the hot spot is totally avoided. Moreover, since the current is cancelled, the power MOSFET doesn't dissipate power and the warming of the junction box is prevented as well.

The new circuit still exploits the voltage across the photovoltaic module to drive the series connected power MOSFET, thus guaranteeing self-activation. The difference with respect to (Daliento et al., 2016) is a special designed driving circuit (see Fig.3), allowing the complete switching OFF of the series MOSFET. As will be shown in the following sections, the behavior of a photovoltaic module equipped with the proposed circuit is, from the terminals point of view, almost identical to that of a photovoltaic module equipped with a standard bypass diode.

The paper is organized as follows. Section II introduces the new circuit in comparison with the previous one. Section III provides a detailed description of the polarization and gives information about realization costs. Section IV describes actual operating modes achieved by means of circuit simulations. Section V reports experimental results. Finally, conclusions are drawn in Section VI.

II. Bypass circuit operating principle

As mentioned above the circuit proposed in this paper is an evolution of the circuit presented in (Daliento et al., 2016). In order to point out differences and new functionalities the previous circuit is shown in Fig. 1b, while the additions proposed in this paper are shown in Fig. 2 and Fig. 3.Only the main features of this topology will be recalled here, more details can be found in (Daliento et al., 2016).

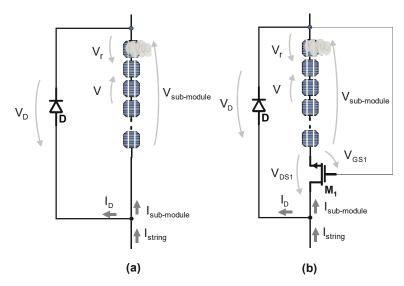


Fig. 1. Series of solar cells protected by standard bypass diode (a) and by an improved bypass circuit subtracting part of the reverse voltage from the shaded cell (b).

As can be seen, the figure shows both the standard arrangement (Fig. 1a), with a bypass diode "protecting" a group of N series connected solar cells (hereinafter referred to as sub-module), and the modified circuit (Fig. 1b), with the MOSFET M_1 connected in series with the sub-module. The most important detail to note is that M_1 is directly driven by the voltage, $V_{\text{sub-module}}$, supplied by the sub-module, which coincides with V_{GS1} . During normal operation (uniform irradiation and no limiting cells) this voltage is positive and quite high (about 10 V since the bypass diode is usually parallel connected to the series of about 20 solar cells). This voltage is high enough to push M_1 in deep conduction where it exhibits a residual resistance of just few milliohms. In other terms, during uniform irradiation the presence of M_1 is negligible and does not affect the behavior of the photovoltaic module. Conversely, when a solar cell limits the current supplied by the module (as an example because it is shadowed), the excess of current coming from the string deviates through the bypass diode, which limits to V_D the voltage at its terminal. Therefore, the reverse voltage across the limiting cell is

$$V_r = (N-1)V + V_D, (1)$$

in the standard case of Fig. 1a, while it is

$$V_r = (N-1)V + V_D - V_{DS1}, \tag{2}$$

in the presence of M_1 .

In (2) (as shown in (Daliento et al., 2016)) V_{DS} weakly depends on the current mismatch, being at least equal to the threshold voltage of M_1 .

The drawback of the circuit of Fig. 1b is that M₁ gets hot in place of the shaded cell.

151 In order to overcome this issue, the circuit shown in Fig. 2 could be adopted.

Two operating modes can be identified. The first corresponds to uniform behavior of all solar cells. In such a case the circuit operation is identical to that of Fig. 1b. Indeed, M_1 operates in deep conductions, so that V_{DS1} is low. As can be seen, V_{DS1} is the driving voltage for M_2 (coincides with the gate-source voltage of M_2), thus M_2 is kept OFF and has no effects on the circuit. The second operating mode occurs in case of current mismatch between I_{string} and $I_{sub-module}$. In such a case a positive feedback activates; indeed, V_{DS1} increases (as in the circuit of Fig. 1b) thus turning ON the MOSFET M_2 , with the consequence that V_{DS2} decreases. Since V_{DS2} coincides with V_{GS1} , M_1 is driven in the OFF state and the current through the submodule is completely interrupted (while the string current, I_{string} , flows through the bypass diode).

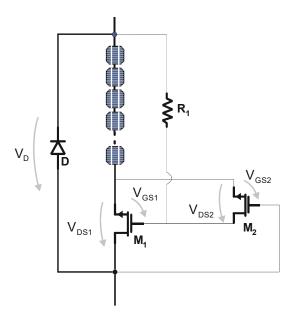


Fig. 2. Improved bypass circuit with a feedback MOSFET M₂ to switch off the sub-module current.

Unfortunately, this very simple solution does not work well because the conduction of M_1 can not be recovered when the current mismatch ceases. In fact, once M_1 has been interdicted, the rising of the current is always prevented, even though the conditions for the bypass are removed.

Therefore, the circuit which is actually proposed in this paper is that of Fig. 3.

As can be seen, the feedback MOSFET M_2 is now driven by the output voltage of a digital oscillator TLC555. The oscillator is power supplied by V_{DS1} . Hence, as long as V_{DS1} is low (normal operation) the oscillator is switched OFF, its output is low and M_2 is OFF as well. When bypass conditions occur, V_{DS1} increases, the oscillator turns ON and starts to provide output signals alternatively high and low. As will

be shown in the next sections the duty cycle of the oscillator is chosen in such a way that the output signal is kept high for about 97% of the time. During this interval of time M_2 is ON and, as a consequence, M_1 is kept OFF. The lowering of the output signal of the oscillator can be seen as an attempt to turn ON M_1 , if bypass conditions are still present when the output of the oscillator returns to high V_{DS1} returns high as well and, for another 97% of the time, the current cannot flow. Conversely, if bypass conditions are no longer present, the attempt to turn ON M_1 succeeds, V_{DS1} falls down, and the oscillator gets switched OFF, thus returning in the normal operating conditions.

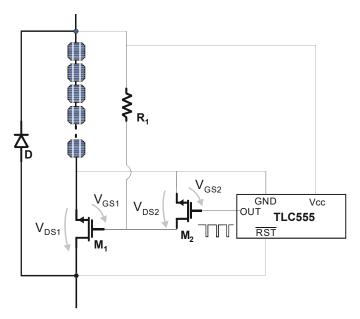


Fig. 3. New bypass circuit for the prevention of the hot spot.

The above solution fully prevents the rising in temperature of shaded cells. Moreover, differently from other approaches, the circuit does not exploit microprocessors or other logic components. It is also important to note that the circuit only consumes a negligible amount of power during bypass events, since the TLC555 is sleeping for the rest of the time.

It is useful to note that the operation of the bypass circuit is strictly related to the architecture of the solar module. The present form was designed for monocrystalline and polycrystalline solar modules, which are made by groups (sub-modules) of series connected solar cells with accessible terminals. The proposed circuit is not suitable for thin film technologies, because those solar panels are made by monolithically integrated solar cells that do not give access to the internal terminals.

However, it is worth to point out that thin film solar panel based on multijunction solar cells can be designed in such a way that each solar cell is provided with its own monolithically integrated bypass diode. In this latter case the solar module is inherently safe and the hot spot is not a concern.

III. Circuit realization and costs

The complete bypass circuit, including all details about its continuous biasing, are reported in Fig.4

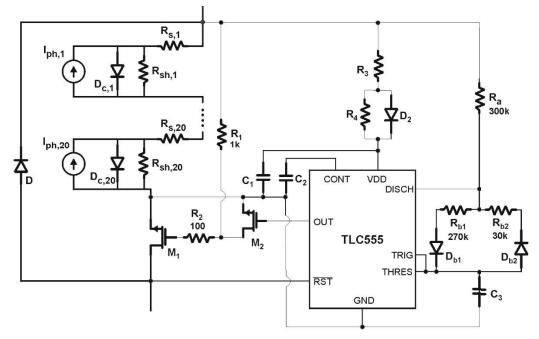


Fig. 4. Detailed circuit schematic of the proposed bypass solution.

As can be inferred, the figure is similar to Fig. 3, with the difference that the solar cells are described by

means of the one diode model (d'Alessandro et al., 2015);the TLC555 is shown along with its polarization network, realized according with the guidelines reported in (Texas Instruments, 2016). In particular, the group formed by R_3 , R_4 , C_1 , and D_2 , supplies the operating voltage to the integrated circuit. The capacitor C_1 , which is connected from V_{DD} and ground (GND), stabilizes the supply voltage. At the start it is rapidly charged through R_3 and D_2 . If the voltage supplied by the solar panel decreases, the discharge of C_1 occurs through the series R_4 - R_3 , so that, choosing an high value for R_4 (the values of all components are reported in Table 1), guarantees slow discharge. It must be remarked that the TLC555 correctly operate with polarization voltages between 2 V and 15 V, this fact means that the solar panel can supply the circuit in all illumination conditions of practical interest. It is also important to point out that the circuit only leaks

The group formed by R_a , R_{b1} , R_{b2} , D_{b1} , D_{b2} , and C_3 , allows setting the frequency of the oscillator and the duty cycle. Formulas for setting these parameters can be found in (Rogers, 2002). By summarizing we can

360 µA for its continuous operation, with a power consumption of few mW.

say that the resistances control the charging and discharging time constants of C_3 , whose oscillating voltage triggers oscillation period T, was chosen to have T=0.63 s, while R_{b2} , related to the duty cycle, was realized by means of a potentiometer allowing to vary the duty cycle in the range 2% - 50%.

 R_1 is chosen to limit the current through M_2 (when M_2 is conducting) to few mA while R_2 is chose to slow down the switching time of M_1 . C_2 stabilizes the threshold for the triggering of the oscillations.

A photograph of the resulting prototype is shown in Fig. 5.



Fig. 5.Rear side photovoltaic module junction box containing three bypass circuits. In the periphery the board contains additional circuits for sensing purposes.

The I-V curve of the solar panel equipped with this prototype (see also Section V) are compared in Fig. 6 with the I-V curve of the same solar panel equipped with the standard bypass diode.

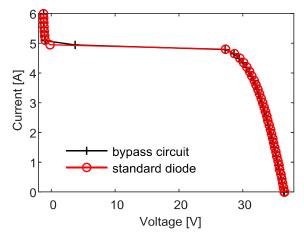


Fig. 6. I-V curves comparison: a 60-cells poly-Si module equipped with standard diodes (red line) is compared to the one adopting the proposed solution (black line).

As can be seen the two curves are almost identical; this means that the bypass circuit does not introduce any disturbance when the solar panel is connected in a series string.

Some details about the cost of the circuit are reported in Table I. The extra cost with respect to the standard bypass diode is about $2 \in$.

TABLE I

Part Name	Description	Unit Price [€]
TLC555	Astable Circuit	0.33^{1}
M_1	N-channel MOFET 40V 100A	0.78^{1}
M_2	N-channel MOFET 30V 2.6 A	0.21
D	Schottky diode 50V 20A	0.42^{1}
Biasing devices	SMD resistors ¼ W, Diodes, Ceramic	0.34
	capacitors	
PCB	Production and Components	0.5
	Soldering	
	Total cost	2.58

¹online catalogue for a quantity of 1000 units.

The incidence of this cost depends on the number of solar cells forming the solar panel. Usually, one bypass device protects about 20 solar cells so that the extra cost is about 0.1 € per solar cell. The incidence of the cost in relation to the producible energy can be evaluated by assuming an expected lifetime for the solar panel of 25 years and a average producible energy of 1300 kWh/kWp/year; for a 5 Wp solar cell this means an extra cost of about 0.0001 €/ kWh. By considering that the cost of a solar cell is about 0.5 €/Wp, the weight of the extra cost per kWh is about 1%.

Another concern for the bypass circuit is reliability. It is quite obvious that adding electronic devices introduces reliability issues; however, in this case, the goal is to bring such issues outside the solar panel, whose value is greater by orders of magnitude. Moreover, it should be considered that adopted power devices are automotive devices rated to handle high currents (100 A) at high switching frequencies (hundred of kHz) with an expected lifetime of several years. The proposed application is for much lower currents and almost stationary operation, so that the expected lifetime becomes much longer than the normal life cycle of the solar panel itself.

IV. Circuit simulation

Simulations were carried out by analyzing the circuit shown in Fig.4. This circuit represents a sub-module made by 20 solar cells; simulations were carried out by connecting in series three of these circuits, thus simulating the behavior of a photovoltaic module made by three sub-modules, hereinafter referred to as #1, #2, and #3. In order to compare the proposed solution with the standard bypass approach, the

MOSFET M_1 belonging to sub-module #1 was short circuited, thus reducing the circuit to that of Fig. 1a. A tracking algorithm, driving the operating point toward the maximum power point (MPP), was also embedded in the simulations.

Simulated experiments were conducted by creating a current mismatch in sub-module #1 and sub-module #3 with respect to sub-module #2, so that the corresponding bypass devices turned ON. The mismatch was caused by assigning a reduced photogenerated current (current sources $I_{ph,i}$ in Fig. 4) to only one solar cell per sub-module, so as to emulate the partial shadowing of sub-modules #1 and #3. As mentioned in the previous section such a situation leads to the reverse biasing of the shaded cells.

The current mismatch was chosen small enough to reproduce the worst conditions in terms of the power dissipated over the shaded cells, as defined by the EN 61215 and corresponding to a small shadow covering the cells. This situation has been also experimentally reproduced, as described in the next section.

The irradiance profile which is supposed to illuminate the solar cells is shown in Fig. 7.

As can be seen, sunny cells are supposed to be subject to a constant irradiance of 1000 W/m² (i.e., 1 Sun), thus supplying their nominal current. In order to test the capability of the new bypass circuit to recognize the occurrence of the shadow, and to recover normal operation when this condition ceases, shaded cells were subject to a varying irradiance, passing from 1000 W/m² to 930 W/m² and vice-versa.

Let's start by analyzing the voltages across each sub-module, shown in Fig. 8.

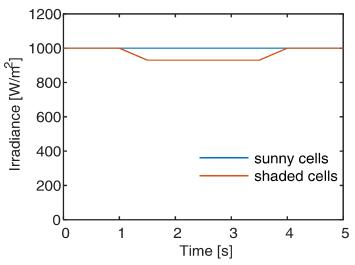


Fig. 7. Simulated irradiance profile adopted to emulate a current mismatch in the photovoltaic module.

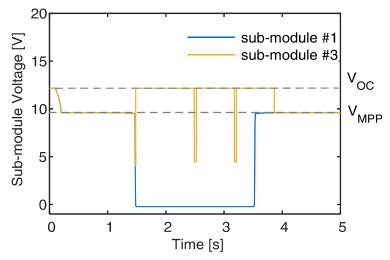


Fig. 8. Voltages supplied by the sub-modules during time varying irradiance conditions depicted in Fig. 6.

As starting condition, t=0, the sub-modules were assumed open circuited, as a consequence, the voltage at their terminals was the open circuit voltage V_{oc} . Subsequently, the MPP Tracking (MPPT) algorithm found the MPP and the voltage decreased to V_{MPP} . At t=1s (see Fig. 7) the irradiance over shaded cells started to decrease and, at about t=1.5s, the current mismatch was large enough to trigger the turn ON of the protection devices. It is important to note that both protection systems turn ON simultaneously, thus evidencing that no delays are introduced by the new circuit. On the other hand, the behavior of the two sub-modules is totally different. In fact, while the voltage across sub-module #1 was small and negative (equal to the voltage drop across the forward biased bypass diode), the voltage across sub-module #3 reached V_{OC} , thus demonstrating that the series MOSFET interrupted the current. As can be seen, the voltage across sub-module #3 decreased periodically, this fact is due to the action of the oscillator that checks the persistence of the bypass conditions, as long as a current mismatch exists the voltage returns to V_{OC} ; conversely, when the mismatch ceases, sub-module #1 promptly recovers V_{MPP} , while sub-module #3 waits for the change of state of the oscillator, after that, V_{MPP} is recovered as well. Therefore, the maximum time allowed for the temperature of the shaded cell to increase is equal to the period of the oscillator.

The effect of the bypass circuits on the shaded cells is better evidenced in Fig. 9.

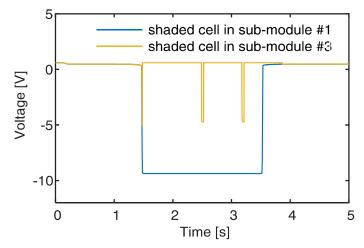


Fig. 9. Voltages across shaded solar cells in sub-modules protected by a standard bypass diode (blue curve) and by the proposed bypass circuit (yellow curve).

As can be seen, during the mismatch, the shaded cell in sub-module #1 was strongly reverse biased (thus heating up), while the shaded cell in sub-module #3 was open circuited for the most part of the time. It is interesting to note that the reverse voltage across the shaded cell in sub-module #3 remains lower than the other also during the shadow checks; this fact depends on the presence of the series MOSFET which shares part of the total voltage, as illustrated in Fig. 1.

Finally, Fig. 10a shows the drain to source voltages, V_{DS} , across the MOSFETs M_1 and M_2 of the bypass circuit, that, according to Fig. 3 coincide, respectively, with the supply voltage of the oscillator and with the driving voltage, V_{GS1} , of M_1 ; while, Fig. 10b reports the output voltage of the oscillator, that coincides the driving voltage of M_2 .

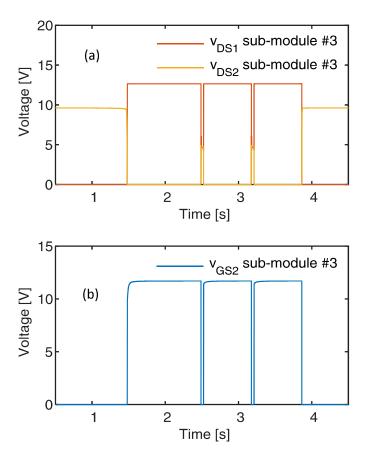


Fig. 10. Driving voltages of the active devices forming the proposed bypass circuit.

During normal operation (no current mismatch), the driving voltage for M_1 (V_{DS2}) is high (equal to V_{MPP}) and V_{DS1} is near zero; when the mismatch occurs (t=1.5s), the oscillator is switched ON and its output signal (V_{GS2} in Fig. 10b) starts to oscillate. When V_{GS2} is high, M_2 is turned ON, as evidenced by V_{DS2} in Fig. 9a that decreases to near zero, consequently M_1 is switched OFF. When V_{GS2} is low (mismatch check) M_1 turns ON, but, if the mismatch is still present, V_{DS1} remains high enough to power supply the oscillator, so that M_1 turns OFF again when V_{GS2} recovers the high value. On the contrary, when the attempt to turn ON M_1 (V_{GS2} low) occurs in absence of current mismatch, V_{DS1} decreases to near zero, so that the oscillator is switched OFF and the normal operation is recovered.

V. Experiments

In order to experimentally verify the performance of the new bypass circuit an electronic board (shown in Fig.5), suitable to be hosted in the standard junction box mounted in the rear side of photovoltaic modules, was designed and fabricated.

The photovoltaic module adopted for the experiments is shown in Fig. 11; it was made by 60 solar cells, grouped in three sub-modules (hereinafter referred to as #1, #2, and #3 as for the simulations), the board contained three separate bypass circuits. In order to test the new circuit in comparison with the standard bypass diode the MOSFET M₁ of the bypass circuit of sub-module #1 was short circuited as in the simulations. Two kinds of experiments were carried out, in the first case a dynamic shadow, advancing and regressing over a solar cell embedded in sub-module #3 was considered. In such a case, the capability of the bypass circuit to recognize the mismatch and to recover the normal operation, was tested. This experiment can be directly compared with the simulations. In the second case, in order to test the capability of the circuit to prevent the hot spot, two solar cells, belonging, respectively, to sub-module #1 and sub-module #3, were partially obscured.

Fig. 11. The 60-cells module adopted for experiments. Second case test set-up: partially shaded solar cells belonging to different sub-modules. The cell on the left is protected by the standard bypass diode, the cell on the right by the new bypass circuit.

In the first case significant electrical parameters were monitored. A photograph of the signals acquired by a digital oscilloscope is shown in Fig. 12.

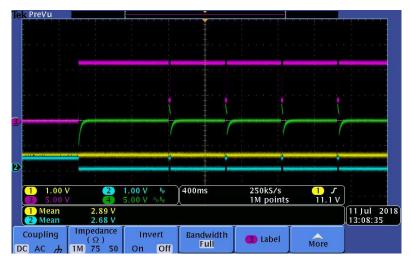


Fig. 12. Digital oscilloscope view of electrical signals during a bypass event.

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The yellow and the blue curves are, respectively, the string current and the current in sub-module #3. The purple and the green curves are, respectively, the drain to source voltage of M₁ and the gate to source voltage of M₁.

To make the interpretation easier, signals are shown separately in the following figures. From these figures it can be derived that the period of the oscillator was set to about 0.6s with duty cycle 96.5%;

364 As can be inferred from Fig. 13a, sub-module #3 was shadowed at about -1.5 s.

hence, the duration of the mismatch check was about 21ms.

The correct intervention of the bypass circuit is witnessed by the interruption of the sub-module current, as well as by V_{DS1}, reported in Fig. 13b, that reached the open circuit voltage. Moreover, the figure shows that the driving voltage of M₁, V_{GS1}, periodically tried to turn ON M₁, but, since shadow was not yet removed, the open circuit condition was promptly recovered when V_{GSI} returned low.

The return to normal operation, when the shadow was removed, is shown in Fig. 14(note that a new 370 timescale is adopted because the figure comes from a new acquisition).

In this case, in the interval of time between 0.5 s and 1s the shadow was removed, so that, after the first time V_{GS1} was made high, at about 1s, M₁ turned ON (V_{DS1} went to zero) and the sub-module supplied again the normal operating current.

The definitive evidence of the correct behavior of the bypass circuit is given by the thermal analysis. The experiment was carried out by applying an opaque shield on two solar cells, as shown in the photograph reported in Fig. 11.

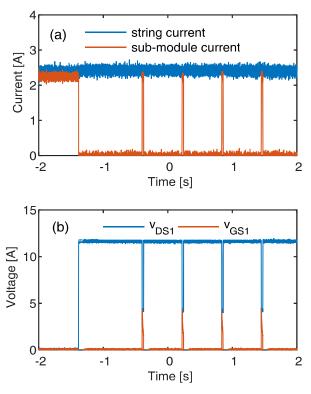


Fig. 13. (a) Currents and (b) voltages measured at the onset of the bypass event.

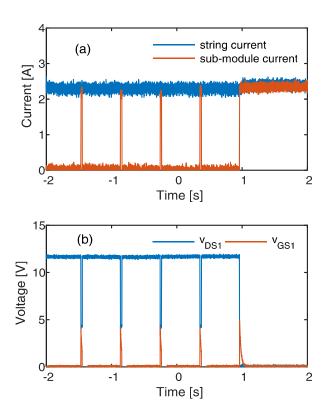


Fig. 14. (a) Currents and (b) voltages measured at the end of the bypass event.

The area of the shields was chosen by following the procedure for the "Hot spot endurance test" described in the EN 61215 to cause the maximum expected power dissipation over the solar cells. The shaded cell in the left side belonged to sub-module #1, hence it was protected by the standard bypass diode only; the shaded cell in the right side belonged to sub-module #3, hence it was protected by the modified bypass circuit. During this experiment the irradiance was about 800 W/m², corresponding to a photogenerated current supplied by the sunny cells of about 6.7 A.

Current and voltages corresponding to such conditions are reported in Fig. 15.

In particular, in Fig. 15a the current supplied by the sunny cells, indicated as "string current", is compared to the currents flowing through the shaded cells. As can be seen, the current flowing through the cell not protected by the bypass circuit is about 5.85 A, coinciding with the current at the maximum power point MPP (according to the operating conditions prescribed by the EN 61215). The current flowing through the cell protected by the bypass circuit is zero, thanks to the opening of the series MOSFET. At the same time, as shown in Fig. 15b, the voltage across the sub-module with the bypass circuit was about 11 V, which is the open circuit voltage (since no current is flowing), while the voltage across the sub-module without the bypass circuit is -0.43 V (because of the intervention of the standard bypass diode). Consequently, the power dissipated by the sub-module equipped with the bypass circuit (Fig. 15c) was zero, while the sub-module not protected by the bypass circuit was dissipating an overall power P of about 2.5 W.

In this regard it is worth noting that, actually, only the shaded solar cell was dissipating power, while the others were working at the MPP. Therefore, the power dissipated by the shaded solar cell can be evaluated by considering that the overall power P produced by the sub-module is given by

$$P = \sum_{i=1}^{20} V_i \cdot I_{string} = 19 \cdot V_{MPP} \cdot I_{string} + V_{Shad} \cdot I_{string}$$
(3)

where V_{shad} is the voltage across the shaded cell. This equation leads to

$$V_{Shad} \cdot I_{string} = P - 19 \cdot V_{MPP} \cdot I_{string} = -55.8W \tag{4}$$

In contrast, the shaded cell protected by the bypass circuit dissipated zero power.

Above results justify the thermal image shown in Fig. 16, taken by means of an IR camera FLUKE TiS56. As can be seen, the solar cell on the left side, not protected by the bypass circuit, got extremely hot, while the solar cell protected by the bypass circuit was cold (the position of the shield can be individuated as a colder area in the white circle). It is interesting to note that the right side of the photovoltaic module (that coincides with sub-module #3) showed an average temperature higher than the left side, this is a further evidence that sub-module #3 operated in open circuit conditions (it is worth remembering that open circuited solar cells do not convert Sun power into electrical power, hence, the operating temperature gets higher). The hot shape on the left, off the photovoltaic module, is the load adopted to fix the operating

416 point.

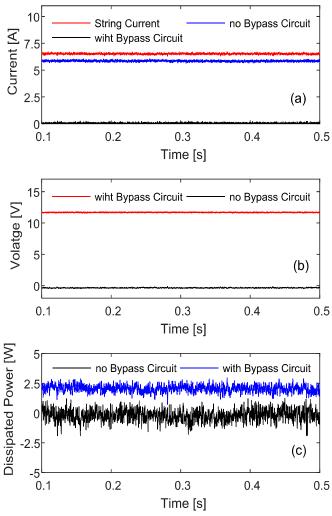


Fig. 15. Currents (a), and voltages (b) corresponding to the shading conditions of Fig. 11. Power dissipation (c) with and without the bypass circuit.

From this figure the temperature profile along a cutting line passing through the center of the two shaded cells has been extracted. This profile, reported in Fig. 17, shows that the hot cell reached a temperature of about 103°C, with a temperature increment of about 50°C with respect to normal operating cells. Conversely, the shaded cell, belonging to sub-module #3 and protected by the new bypass circuit, remained at the normal operating temperature, with an expected small increment on the exposed surface depending on the open-circuit operation.

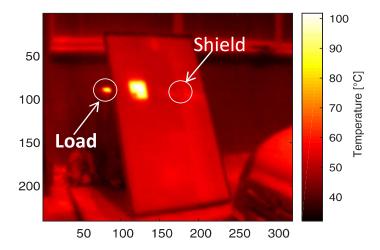


Fig. 16.Thermal image of the partially shaded photovoltaic module shown in Fig.13.

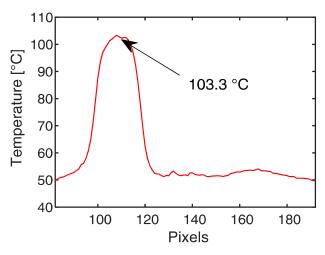


Fig. 17. Thermal profile along a cutting line passing through the center of the shaded solar cells.

VI. Conclusions

In this paper a new bypass circuit has been presented. The circuit prevents the formation of hot spots in malfunctioning solar cells by interrupting the current circulating in the corresponding sub-module, thus inhibiting power dissipation. With respect to other solutions based on the same principle, the proposed circuit has an "analogical" behavior, in the sense that it is self-activating when mismatch conditions occur, without needing micro-processors or other complex logic circuits. Simulations and experiments have evidenced that the hot spot can be effectively prevented. In the worst case operating conditions, as defined by the EN 61215, a difference of about50 °C, has been found between a shaded solar cell protected by a

- standard bypass diode and, in the same operating conditions, a solar cell protected by the new bypass
- 446 circuit.

- 448 References
- 449 AN3432 ST Application note [WWW Document], 2011. https://doi.org/019041 Rev 1
- Bressan, M., Gutierrez, A., Garcia Gutierrez, L., Alonso, C., 2018. Development of a real-time hot-spot
- prevention using an emulator of partially shaded PV systems. Renew. Energy 127, 334–343.
- 452 https://doi.org/10.1016/j.renene.2018.04.045
- d'Alessandro, V., Di Napoli, F., Guerriero, P., Daliento, S., 2015. An automated high-granularity tool for
- a fast evaluation of the yield of PV plants accounting for shading effects. Renew. Energy 83, 294–
- 455 304.
- d'Alessandro, V., Guerriero, P., Daliento, S., 2014. A simple bipolar transistor-based bypass approach for photovoltaic modules. IEEE J. Photovoltaics 4, 505–513.
- Daliento, S., Di Napoli, F., Guerriero, P., d'Alessandro, V., 2016. A modified bypass circuit for improved
- hot spot reliability of solar panels subject to partial shading. Sol. Energy 134.
- 460 https://doi.org/10.1016/j.solener.2016.05.001
- Dhimish, M., Holmes, V., Mather, P., Sibley, M., 2018. Novel hot spot mitigation technique to enhance
- photovoltaic solar panels output power performance. Sol. Energy Mater. Sol. Cells 179, 72–79.
- https://doi.org/10.1016/j.solmat.2018.02.019
- García, M., Marroyo, L., Lorenzo, E., Marcos, J., Pérez, M., 2013. Observed degradation in photovoltaic
- plants affected by hot-spots. Prog. Photovoltaics Res. Appl. 24, 1292–1301.
- 466 https://doi.org/10.1002/pip.2393
- Ghanbari, T., 2017. Hot spot detection and prevention using a simple method in photovoltaic panels. IET
- 468 Gener. Transm. Distrib. 11, 883–890. https://doi.org/10.1049/iet-gtd.2016.0794
- Green, M.A., 1986. Solar cells : operating principles, technology and system applications. University of
- 470 New South Wales., Kensington.
- 471 Jordan, D.C., Kurtz, S.R., 2013. Photovoltaic Degradation Rates-an Analytical Review. Prog.
- 472 Photovoltaics Res. Appl. 21, 12–29. https://doi.org/10.1002/pip.1182
- Kaplani, E., 2012. Detection of degradation effects in field-aged c-Si solar cells through IR thermography
- and digital image processing. Int. J. Photoenergy 2012. https://doi.org/10.1155/2012/396792
- Kim, K.A., Krein, P.T., 2015. Reexamination of Photovoltaic Hot Spotting to Show Inadequacy of the
- Bypass Diode. IEEE J. Photovoltaics 5, 1435–1441.
- 477 https://doi.org/10.1109/JPHOTOV.2015.2444091
- 478 Kim, K.A., Krein, P.T., Seo, G.S., Cho, B.H., 2013. Photovoltaic AC parameter characterization for
- dynamic partial shading and hot spot detection. Conf. Proc. IEEE Appl. Power Electron. Conf.
- 480 Expo. APEC 2, 109–115. https://doi.org/10.1109/APEC.2013.6520194
- Niazi, K., Khan, H.A., Amir, F., 2018. Hot-spot reduction and shade loss minimization in crystalline-
- 482 silicon solar panels. J. Renew. Sustain. Energy 10, 033506. https://doi.org/10.1063/1.5020203
- 483 Olalla, C., Hasan, M., Deline, C., Maksimović, D., 2018. Mitigation of Hot-Spots in Photovoltaic Systems

484	Using Distributed Power Electronics. Energies 11, 726. https://doi.org/10.3390/en11040726
485	Philipps, S., Warmuth, W., 2018. PHOTOVOLTAICS REPORT [WWW Document].
486 487	Rogers, P., 2002. Design low-duty-cycle timer circuits [WWW Document]. Bill Travis. URL www.edn.com
488 489 490	Sanchez-Friera, P., Piliougine, M., Pelaez, J., Carretero, J., Cardona, M.S. de, 2011. Analysis of degradation mechanisms of crystalline silicon PV modules after 12 years of operation in Southern Europe. Prog. PHOTOVOLTAICS Res. Appl. 19, 658–666. https://doi.org/10.1002/pip.1083
491 492 493	Spanoche, S.A., Stewart, J.D., Hawley, S.L., Opris, I.E., 2013. Model-Based Method for Partially Shaded PV Module Hot-Spot Suppression. IEEE J. Photovoltaics 3, 785–790. https://doi.org/10.1109/JPHOTOV.2012.2230054
494 495	Texas Instruments, 2016. TLC555 LinCMOS Timer [WWW Document]. URL http://www.ti.com/lit/ds/symlink/tlc555.pdf
496	